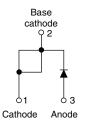


# VS-20TQ0..PbF Series, VS-20TQ0..-N3

**Vishay Semiconductors** 

# Schottky Rectifier, 20 A





PRODUCT SUMMARY						
Package	TO-220AC					
I <sub>F(AV)</sub>	20 A					
V <sub>R</sub>	35 V, 40 V, 45 V					
V <sub>F</sub> at I <sub>F</sub>	0.51 V					
I <sub>RM</sub> max.	105 mA at 125 °C					
TJ	150 °C					
Diode variation	Single die					
E <sub>AS</sub>	27 mJ					

## **FEATURES**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- · High frequency operation



• High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- · Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and gualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

## DESCRIPTION

The VS-20TQ... Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I <sub>F(AV)</sub>	Rectangular waveform	20	A					
V <sub>RRM</sub>	Range	35 to 45	V					
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1800	A					
V <sub>F</sub>	20 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.51	V					
TJ	Range	- 55 to 150	°C					

VOLTAGE RATINGS										
PARAMETER	SYMBOL	VS- 20TQ035PbF	VS- 20TQ035-N3	VS- 20TQ040PbF	VS- 20TQ040-N3	VS- 20TQ045PbF	VS- 20TQ045-N3	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>									
Maximum working peak reverse voltage	V <sub>RWM</sub>	35	35	40	40	45	45	V		

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS				
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	$I_{F(AV)}$ 50 % duty cycle at T <sub>C</sub> = 116 °C, rectangular waveform							
Maximum peak one cycle non-repetitive surge current	Irou	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with rated	1800	А				
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	$V_{\text{RRM}}$ applied	400					
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25 \text{ °C}, I_{AS} = 4 \text{ A}, L = 3.4 \text{ m}$	27	mJ					
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zer Frequency limited by $T_J$ maxim	4	А					

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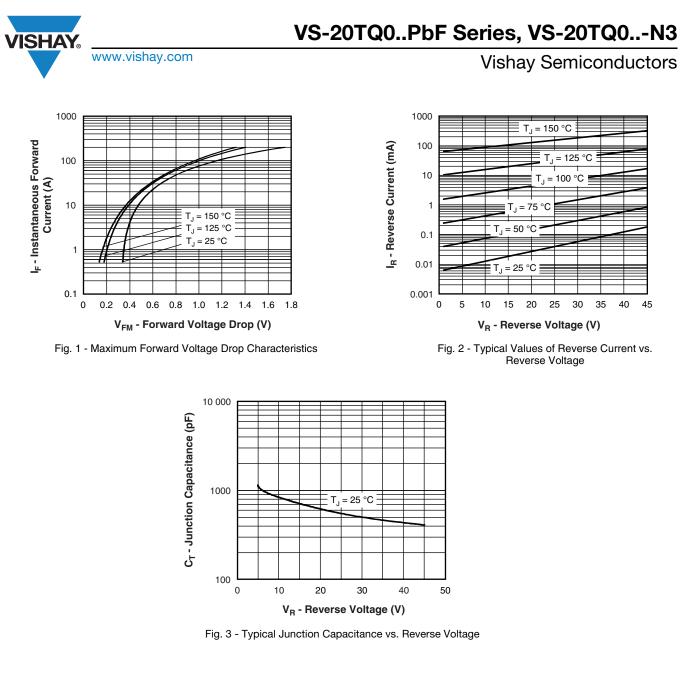
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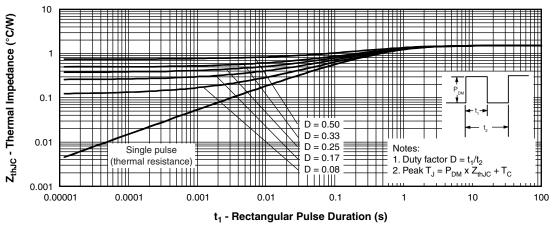
ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
		20 A	T <sub>.1</sub> = 25 °C	0.57				
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	40 A	1j=25 0	0.73	V			
See fig. 1	¥FM (*)	20 A	T <sub>.1</sub> = 125 °C	0.51				
		40 A	1j = 125 C	0.67				
Maximum reverse leakage curent	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	2.7	٣A			
See fig. 2		T <sub>J</sub> = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	105	mA			
Maximum junction capacitance	CT	$V_{R}$ = 5 $V_{DC}$ , (test signal range 100 kHz to 1 MHz) 25 °C		1400	pF			
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 m	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	Rated V <sub>R</sub>					

### Note

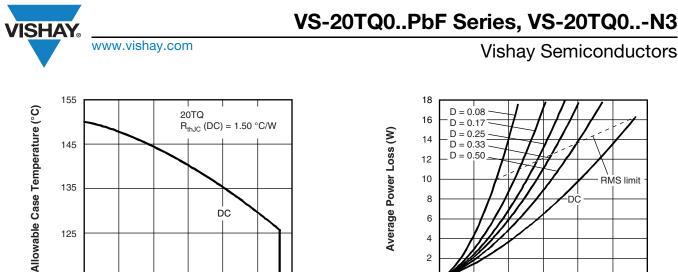
 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2  $\,\%$ 

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 150	°C					
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation See fig. 4	1.50	°C/W					
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	0,00					
Approximate weight			2	g					
Approximate weight			0.07	oz.					
Mounting torque			6 (5)	kgf ⋅ cm					
Mounting torque maximum			12 (10)	(lbf · in)					
			20TQ035						
Marking device		Case style TO-220AC	20TQ040						
			20TQ045						











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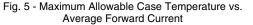
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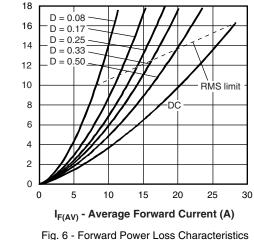
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115 0

5

10





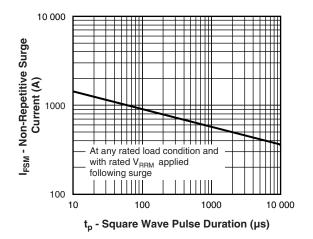


Fig. 7 - Maximum Non-Repetitive Surge Current

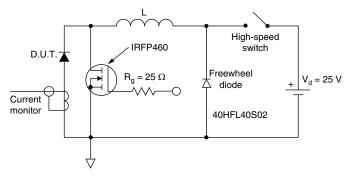


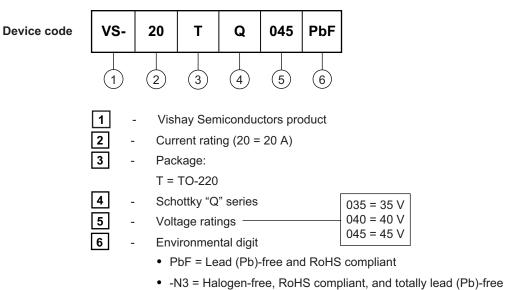
Fig. 8 - Unclamped Inductive Test Circuit

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## **ORDERING INFORMATION TABLE**



ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-20TQ035PbF	50	1000	Antistatic plastic tube							
VS-20TQ035-N3	50	1000	Antistatic plastic tube							
VS-20TQ040PbF	50	1000	Antistatic plastic tube							
VS-20TQ040-N3	50	1000	Antistatic plastic tube							
VS-20TQ045PbF	50	1000	Antistatic plastic tube							
VS-20TQ045-N3	50	1000	Antistatic plastic tube							

LINKS TO RELATED DOCUMENTS						
Dimensions		www.vishay.com/doc?95221				
Deut medice information	TO-220AC PbF	www.vishay.com/doc?95224				
Part marking information	TO-220AC -N3	www.vishay.com/doc?95068				



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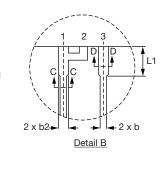
**TO-220AC** 

plane

## **DIMENSIONS** in millimeters and inches









**Diodes** 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220AC

SYMBOL	MILLIN	IETERS	INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES	
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES		STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183			E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055			E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115			е	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040			e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4		H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068			L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4		L1	3.32	3.82	0.131	0.150	2
с	0.36	0.61	0.014	0.024			L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4		L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3		ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355			Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6		θ	90° t	o 93°	90° t	o 93°	
E	10.11	10.51	0.398	0.414	3, 6							

Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

- <sup>(2)</sup> Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- <sup>(4)</sup> Dimension b1, b3 and c1 apply to base metal only
- <sup>(5)</sup> Controlling dimension: inches
- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2 and E1
- <sup>(7)</sup> Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- <sup>(8)</sup> Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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